

## **ZHT431**

# Adjustable precision Zener shunt regulator

## **Description**

The ZHT431 is a three terminal adjustable shunt regulator offering excellent temperature stability and output current handling capability up to 100mA. The device offers extended operating temperature range working from -55 to +125°C. The output voltage may be set to any chosen voltage between 2.5 and 20 volts by selection of two external divider resistors.

**Features** 

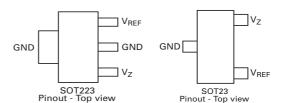
- Surface mount SOT223 and SOT23 packages
- 2% and 1% tolerance
- Maximum temperature coefficient 67 ppm/°C
- Temperature compensated for operation over the full temperature range
- · Programmable output voltage
- 50μA to 100mA current sink capability
- · Low output noise
- Wide temperature range -55 to +125°C

The devices can be used as a replacement for zener diodes in many applications requiring an improvement in zener performance.

## **Applications**

- · Series and shunt regulator
- · Voltage monitor
- Over voltage / under voltage protection
- Switch mode power supplies

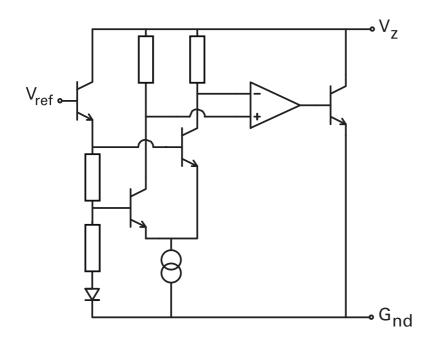
### **Pinout information**



## **Ordering information**

Order reference	Tolerance (%)	Package	Part mark	Status	Reel size (inches)	Quantity per reel	Tape width
ZHT431C01L	1	TO92	ZHT43101	Obsolete	Loose	4000	=
ZHT431C01STOB	1	TO92	ZHT43101	Obsolete	12.5	1500	=
ZHT431C01STZ	1	TO92	ZHT43101	Obsolete	Concertina	1500	-
ZHT431C02L	2	TO92	ZHT43102	Obsolete	Loose	4000	=
ZHT431C02STOB	2	TO92	ZHT43102	Obsolete	12.5	1500	-
ZHT431C02STZ	2	TO92	ZHT43102	Obsolete	Concertina	1500	-
ZHT431F01TA	1	SOT23	43C	Released	7	3000	8mm
ZHT431F02TA	2	SOT23	43D	Released	7	3000	8mm
ZHT431G01TA	1	SOT223	ZHT43101	Released	7	1000	12mm
ZHT431G02TA	2	SOT223	ZHT43102	Released	7	1000	12mm

# Schematic diagram



# Absolute maximum rating

Cathode voltage (V <sub>Z</sub> )	20V	Power dissipation	on (T <sub>amb</sub> =25°C)
Cathode current	150mA	$(T_{jmax} = 150^{\circ}C)$	
Operating temperature	-55 to 125°C	SOT23	330mW
Storage temperature	-55 to 150°C	TO92	780mW
		SOT223	2W

## **Recommended operating conditions**

	Min.	Max.
Cathode voltage	$V_{REF}$	20V
Cathode current	50μΑ	100mA

# Electrical characteristics test conditions (unless otherwise stated):T<sub>amb</sub>=25°C

Symbol	Parameter		Value		Units	Conditions
		Min.	Тур.	Max.		
$V_{REF}$	Reference voltage 2%	2.45	2.50	2.55	V	I <sub>L</sub> =10mA (Fig.1),
	1%	2.475	2.50	2.525	V	$V_Z=V_{REF}$
V <sub>DEV</sub>	Deviation of reference input voltage over temperature		10	30	mV	I <sub>L</sub> =10mA, V <sub>Z</sub> =V <sub>REF</sub> T <sub>amb</sub> =full range (Fig1)
$\frac{\Delta V_{REF}}{\Delta V_Z}$	$\frac{\Delta V_{REF}}{\Delta V_Z}$ Ratio of the change in reference voltage to the change in cathode voltage		-1.85	-2.7	mV/V	$V_Z$ from $V_{REF}$ to 10V $I_Z$ =10mA (Fig.2)
			-1.0	-2.0	mv/V	$V_Z$ from 10V to 20V $I_Z$ =10mA (Fig.2)
I <sub>REF</sub>	Reference input current		0.12	1.0	μΑ	R1=10k, R2=O/C, I <sub>L</sub> =10mA (Fig.2)
$\Delta I_{REF}$	Deviation of reference input current over temperature		0.04	0.2	μΑ	R1=10k, R2=O/C, I <sub>L</sub> =10mA T <sub>amb</sub> =full range (Fig.2)
I <sub>Zmin</sub>	Minimum cathode current for regulation		35	50	μΑ	V <sub>Z</sub> =V <sub>REF</sub> (Fig.1)
I <sub>Zoff</sub>	Off-state current			0.1	μΑ	V <sub>Z</sub> =20V, V <sub>REF</sub> =0V(Fig.3)
R <sub>Z</sub>	Dynamic output impedance			0.75	Ω	V <sub>Z</sub> =V <sub>REF</sub> (Fig.1), f=0Hz, I <sub>C</sub> =1mA to 100mA

Deviation of reference input voltage,  $V_{DEV}$ , is defined as the maximum variation of the reference input voltage over the full temperature range.

The average temperature coefficient of the reference input voltage, V<sub>REF</sub> is defined as:

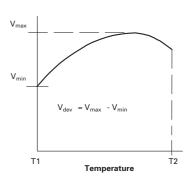
$$V_{REF}\left(\frac{ppm}{{}^{\circ}C}\right) = \frac{V_{DEV}x1000000}{V_{REF}(T1-T2)}$$

The dynamic output impedance, R<sub>Z</sub>, is defined as:

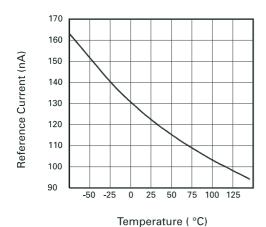
$$R_Z = \frac{\Delta V_Z}{\Delta I_Z}$$

When the device is programmed with two external resistors, R1 and R2, (fig 2) , the dynamic output impedance of the overall circuit, R', is defined as:

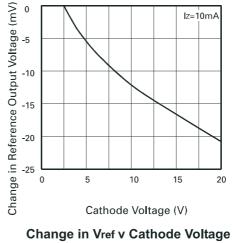
$$R' = R_Z(1 + \frac{R1}{R2})$$

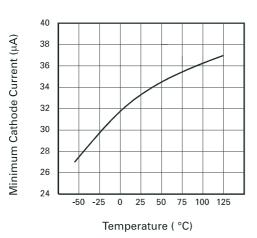


## **Typical characteristics**

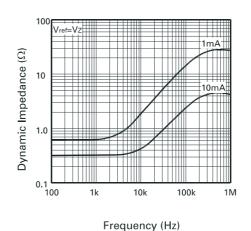


Iref vs. Temperature

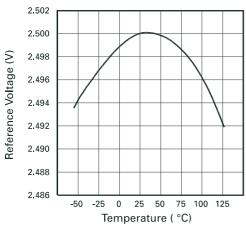




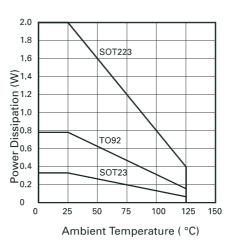
Izmin vs. Temperature



**Dynamic Impedance v Frequency** 

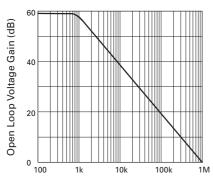


Vref vs. Temperature



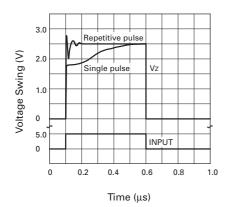
**Power Dissipation Derating** 

# **Typical characteristics**

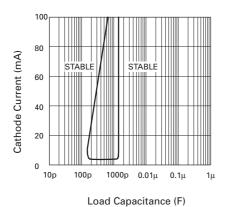


Frequency (Hz)

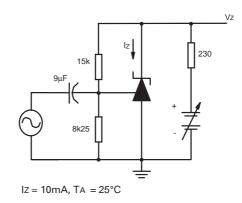
### Gain v Frequency



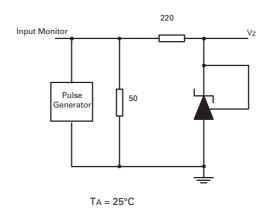
**Pulse Response** 



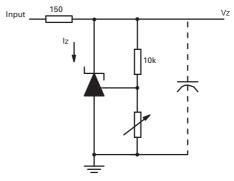
**Stability Boundary Conditions** 



Test Circuit for Open Loop Voltage Gain



**Test Circuit for Pulse Response** 



Vref < VZ < 20, IZ = 10mA, TA = 25°C

**Test Circuit for Stability Boundary Conditions** 

## **DC** test circuits

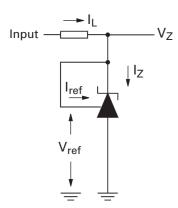


Fig 1 - Test circuit for  $V_Z = V_{ref}$ 

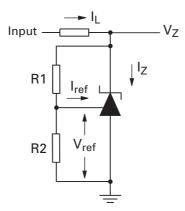


Fig 2 - Test circuit for  $V_Z > V_{ref}$ 

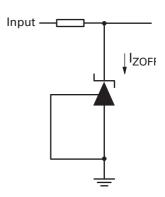
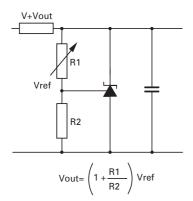
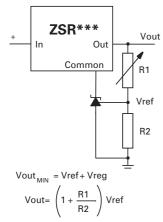


Fig 3 - Test circuit for for Ol state current<sup>†</sup>

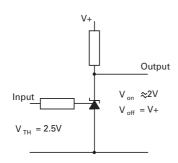
# **Application circuits**



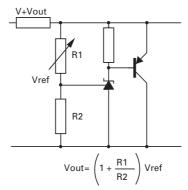
**Shunt regulator** 



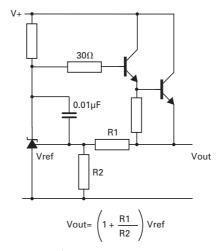
Output control of a three terminal fixed regulator



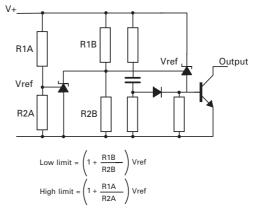
Single supply comparator with temperature compensated threshold



Higher current shunt regulator

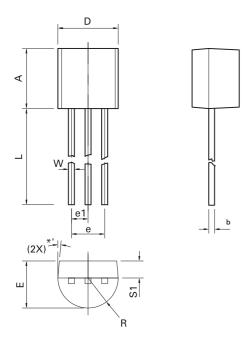


Series regulator



Over voltage / under voltage protection circuit

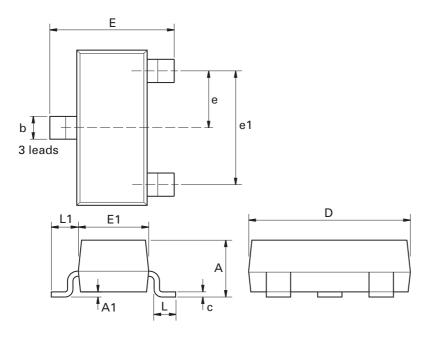
# Package outline - TO92



DIM	Millimeters		Inc	hes
	Min.	Max.	Min.	Max.
Α	4.32	4.95	0.170	0.195
b	0.36	0.51	0.014	0.020
E	3.30	3.94	0.130	0.155
е	2.41	2.67	0.095	0.105
e1	1.14	1.40	0.045	0.055
L	12.70	15.49	0.500	0.610
R	2.16	2.41	0.085	0.095
S1	1.14	1.52	0.045	0.060
W	0.41	0.56	0.016	0.022
D	4.45	4.95	0.175	0.195
*0	4°	6°	4°	6°

Note: Controlling dimensions are in millimeters. Approximate dimensions are provided in inches

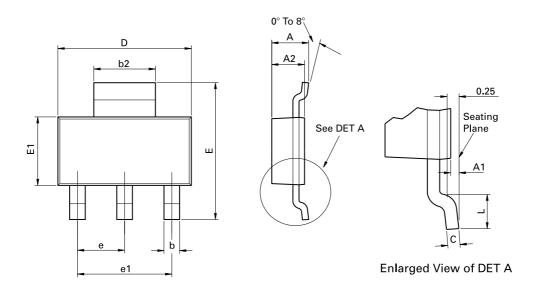
# Package outline - SOT23



Dim.	Millin	neters	Inc	hes	Dim.	Millin	neters	Inc	hes
	Min.	Max.	Min.	Max.		Min.	Мах.	Min.	Max.
Α	-	1.12	-	0.044	e1	1.90	NOM	0.075	NOM
A1	0.01	0.10	0.0004	0.004	Е	2.10	2.64	0.083	0.104
b	0.30	0.50	0.012	0.020	E1	1.20	1.40	0.047	0.055
С	0.085	0.20	0.003	0.008	L	0.25	0.60	0.0098	0.0236
D	2.80	3.04	0.110	0.120	L1	0.45	0.62	0.018	0.024
е	0.95	NOM	0.037	NOM	-	-	-	-	-

Note: Controlling dimensions are in millimeters. Approximate dimensions are provided in inches

# Package outline - SOT223



Conforms to JEDEC TO-261 AA Issue B

Dim.	Millin	neters	Inc	hes	Dim.	es		neters	Inc	hes
Dilli.	Min.	Max.	Min.	Max.		Min.	Max.	Min.	Max.	
Α	-	1.80	-	0.071	D	6.30	6.70	0.248	0.264	
A1	0.02	0.10	0.0008	0.004	е	2.30	BSC	0.090	5 BSC	
A2	1.55	1.65	0.0610	0.0649	e1	4.60 BSC		0.181 BSC		
b	0.66	0.84	0.026	0.033	Е	6.70	7.30	0.264	0.287	
b2	2.90	3.10	0.114	0.122	E1	3.30	3.70	0.130	0.146	
С	0.23	0.33	0.009	0.013	L	0.90	-	0.355	-	

Note: Controlling dimensions are in millimeters. Approximate dimensions are provided in inches

# **ZHT431**

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